INFORMATION CITED BY APPLICANT(S) THAT MAY BE MATERIAL TO THE PROSECUTION OF THE SUBJECT APPLICATION

Applicant:

F.M. Schellenberg et al.

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U.S. PATENT DOCUMENTS

Bot	U1	5,364,716	11/15/1994	Nakagawa et al.
	U2	5,573,890	11/12/1996	Spence
	U3	5,636,131	06/03/1997	Liebmann et al.
	U4	5,663,017	. 09/02/1997	Schinella et al.
	U5	5,702,848	12/30/1997	Spence
	U6	5,766,804	06/16/1998	Spence
	U7	5,766,806	06/16/1998	Spence

	UJ	3,702,040	12/30/1997	Spence
	U6	5,766,804	06/16/1998	Spence
	U7	5,766,806	06/16/1998	Spence
	U8	5,807,649	09/15/1998	Liebmann et al.
	U9	5,858,580	01/12/1999	Wang et al.
	U10	5,867,401	02/02/1999	Haruki
	U11	6,132,908	10/17/2000	Shiraishi et al.
	U12	6,493,866	12/10/2002	Mayhew
	U13	6,503,666	01/07/2003	Pierrat
	U14	6,524,752	02/25/2003	Pierrat
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LAW OFFICES OF
CHRISTENSEN O'CONNOR JOHNSON KINDNESS**
1420 Fifth Avenue
Suite 2800
Seattle, Washington 98101
206.682.8100

Pierrat et al.

FOREIGN PATENT DOCUMENTS

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*Examiner Cite Initial No.	Document No.	Kind Code	Publication Date (mm/dd/yyyy)	Country	English Abstract Translation Provided Provided
136 F1	DE 41 21 564	Al	01/09/1992	Germany	
_ 725 F2	EP 0 698 916	A2	02/28/1996	EPO	
Por F3	WO 99/14636	Al	03/25/1999	PCT	

OTHER INFORMATION (Including Author, Title, Date, Pertinent Pages, Etc.)

*Examiner Initial	ID	
<u>ha</u>	O1	Marc D. Levenson, Improving Resolution in Photolithography with a Phase-Shifting Mask, IEEE TRANSACTIONS ON ELECTRON DEVICES, Vol. ED-29, No. 12, December 1982.
155	O2	Hideyuki Jinbo and Yoshio Yamashita, Improvement of Phase-Shifter Edge Line Mast Method, Japanese Journal of Applied Physics, Vol. 30, No. 11B, November 1991, pp. 2998-3003.
<u>h</u> 50	O3	Kazuyuki Inokuchi, Tadashi Saito, Hideyuki Jinbo, Yoshio Yamashita, and Yoshiaki Sano, Sub-Quarter Micron Gate Fabrication Process Using Phase-Shifting Mask for Microwave GaAs Devices, JAPANESE JOURNAL OF APPLIED PHYSICS, Vol. 30, No. 12B, December 1991, pp. 3818-3821.
167	04	B. J. Lin, <i>Phase-Shifting Masks Gain an Edge</i> , IEEE CIRCUITS & DEVICES, March 1993, pp. 28-35.
150	O5	Marc D. Levenson, Wavefront Engineering for Photolithography, PHYSICS TODAY, July 1993.

OTHER INFORMATION (Including Author, Title, Date, Pertinent Pages, Etc.)

*Examiner Initial	ID	
121	06	Harafuji, Kenji et al., "A Novel Hierarchical Approach for Proximity Effect Correction in Electron Beam Lithography," IEEE Transaction on Computer-Aided Design of Integrated Circuits and Systems, <i>IEEE</i> 12(10):1508-1514, New York, October 10, 1993.
Exam	niner	Date Considered
	3	Med 12/20/05
		: Initial if reference considered, whether or not citation is in conformance with
•	-	lraw line through citation if not in conformance and not considered. Include with next communication to applicant.